



AP7369Q

WIDE INPUT-VOLTAGE RANGE 150mA ULDO REGULATOR

Description

The AP7369Q series is a wide input-voltage range (45V), low quiescent current ($2.1\mu A$), low-dropout linear regulator (LDO) able to provide 150mA load current.

The device provides a very fast response against line voltage transient and load current transient, and ensures no overshoot voltage occurs during startup and short-circuit recovery. It also features integrated short-circuit and thermal-shutdown protection.

The AP7369Q has 2.5V, 3.3V, and 5.0V fixed output voltage versions. It is available in the SOT25 and SOT223 packages.

Features

- Wide Input-Voltage Range: 3V to 45V
- Maximum Output Current: 150mA
- Low Dropout Voltage:

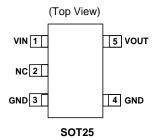
 $V_{DROP} = 35mV @ I_{OUT} = 10mA (typ)$

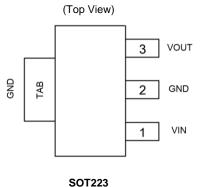
 $V_{DROP} = 350 \text{mV} @ I_{OUT} = 100 \text{mA} \text{ (typ)}$

- Low Quiescent Current: 2.1µA (typ)
- Fixed Output Voltages: 2.5V, 3.3V and 5.0V
- High Output Voltage Accuracy: ±2%
- High PSRR: 85dB@1kHz
- Excellent Line/Load Regulation
- Thermal Shutdown Function
- Short-Current Protection Function
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The AP7369Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Pin Assignments





Applications

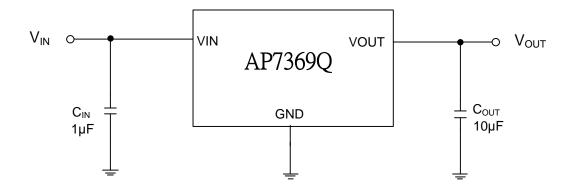
- Powering MCUs and CAN/LIN transceivers
- Automotive head units
- EV and HEV battery management systems
- Body control modules
- Transmission control units (TCUs)

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Applications Circuit

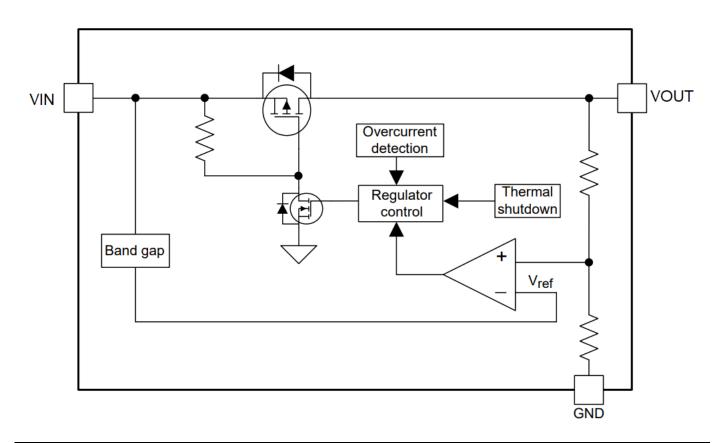


Pin Descriptions

Pin N	umber		
SOT25	SOT223	Pin Name	Function
1	1	VIN	Input voltage
2	_	NC	Not connected internally, recommend connect to GND to maximize PCB copper for thermal dissipation.
3, 4	2	GND	Ground
5	3	VOUT	Regulated output voltage
_	TAB	Expose Pad	In PCB layout, prefer to use large copper area to cover this pad for better thermal dissipation, then connect this area to GND or leave it open. However, do not use it as GND electrode function alone.



Functional Block Diagram



Absolute Maximum Ratings (Notes 4 and 5)

Symbol	Parameter	Rating	Unit
VIN	Supply Input Voltage	-0.3 to 55	V
V _{OUT}	Regulated Output Voltage	-0.3 to 6	V
V_{EN}	EN to GND	-0.3 to 55	V
Іоит	Output Current	Internally Limited	mA
TLEAD	Lead Temperature (Soldering, 10sec)	+260	°C
TJ	Operating Junction Temperature	+150	°C
TA	Operating Ambient Temperature	-40 to +125	°C
T _{STG}	Storage Temperature Range	-40 to +150	°C
CDM	ESD (Charged Device Model)	±1.5	kV
НВМ	ESD (Human Body Model)	3	kV

Notes:

Stresses beyond those listed under Absolute Maximum Ratings can cause permanent damage to the device. These are stress ratings only and functional operation of the device at these conditions is not implied. Exposure to absolute-maximum-rated conditions for extended period can affect device reliability.
Ratings apply to ambient temperature at +25°C. The JEDEC STD.51 High-K board design used to derive this data was a 3inch x 3inch multilayer board with 1oz. internal power and ground planes and 2oz. copper traces on the top and bottom of the board.



Recommended Operating Conditions

Symbol	Parameter	Min	Тур	Max	Unit
Vin	Supply Input Voltage	3.0	_	45	٧
Vouт	Output Voltage	_	_	5	V
TJ	Operating Junction Temperature	-40	_	+150	°C
Cin	Input Capacitor	_	1	_	μF
Соит	Output Capacitor	2.2	_	100	μF

Package Thermal Information (Note 5)

	THERMAL METRIC		SOT233	UNIT
Reja	Junction-to-ambient thermal resistance	159.89	104.59	°C/W
R _θ JC(top)	Junction-to-case (top) thermal resistance	64.45	89.11	°C/W
Rејв	Junction-to-board thermal resistance	89.72	52.3	°C/W
Ψлт	Junction-to-top characterization parameter	19.49	32.44	°C/W
ΨЈВ	Junction-to-board characterization parameter	88.86	67.12	°C/W
ReJC(bot)	Junction-to-case (bottom) thermal resistance	60.05	50.17	°C/W

Note: 5. Ratings apply to ambient temperature at +25°C. The JEDEC STD.51 High-K board design used to derive this data was a 3inch x 3inch multilayer board with 1oz. internal power and ground planes and 2oz. copper traces on the top and bottom of the board.

$\textbf{Electrical Characteristics} \ (@T_A = -40 ^{\circ}C \ to \ +125 ^{\circ}C, \ I_{OUT} = 1 \text{mA}, \ C_{IN} = 1 \mu\text{F}, \ C_{OUT} = 10 \mu\text{F} \ \underline{\text{ceramic capacitor}}, \ V_{IN} = 14 \text{V})$

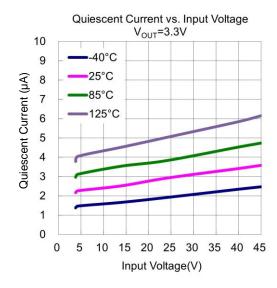
Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
Vin	Input Voltage	_	3	_	45	V
IGND	Quiescent Current	No Load	_	2.1	8	μΑ
Vouт	Output Voltage	IOUT = 10mA	Vоитх98%	_	V _{ОUТ} х102%	V
I _{OUT_MAX}	Output Current	_	150	_	_	mA
		I _{OUT} = 10mA, V _{IN} = V _{OUTNOM} - 0.1V	_	35	80	mV
VDROP	V _{DROP} Dropout Voltage (Note 6)	IOUT = 100mA, VIN = VOUTNOM - 0.1V	_	350	800	mV
		IOUT = 150mA, VIN = VOUTNOM - 0.1V	_	1000	1200	mV
ΔVουτ(ΔΙουτ)	Load Regulation (Note 7)	1mA ≤ I _{OUT} ≤ 100mA	_	0.02	0.025	%/mA
ΔVουτ(ΔVIN)	Line Regulation	VOUTNOM + 2V ≤ VIN ≤ 45V, IOUT = 1mA	_	0.01	0.02	%/V
ILIMIT	Current Limit	_	150	_	500	mA
Totsd	Thermal Shutdown Temperature	_	_	+175	_	°C
THYOTSD	Thermal Shutdown Hysteresis	_	_	+25	_	°C
PSRR	Power Supply Rejection Ratio	Iout = 10mA, Vout = 3.3V@1kHz	_	85	_	dB
Vn	Output Noise Voltage	BW = 10Hz to 100kHz, Iout = 30mA	_	120	_	μVrms

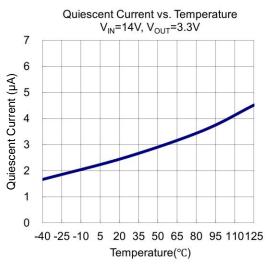
6. Dropout voltage is the voltage difference between the input and output at which the output voltage drops 100mV below its nominal value. This parameter only applies to output voltages above 3.0V since minimum V_{IN} = 3.0V.

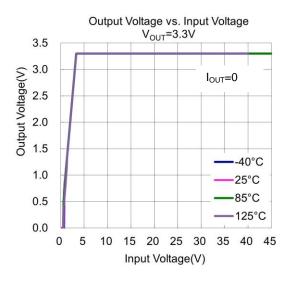
^{7.} The AP7369Q internal circuitry is not fully operational until V_{IN} is at least the greater of 3V or (V_{OUT}+V_{DROPOUT(MAX)}).

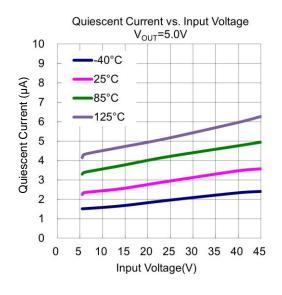


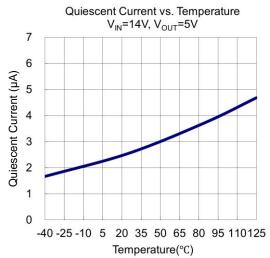
Performance Characteristics

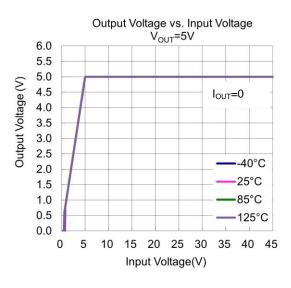




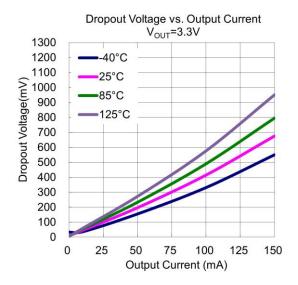


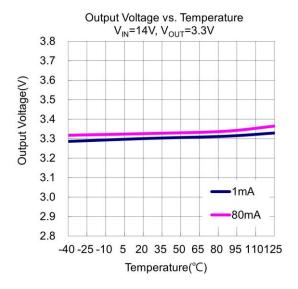


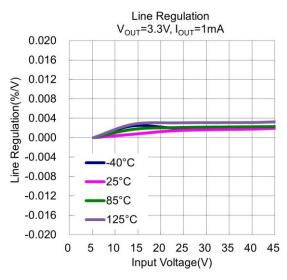


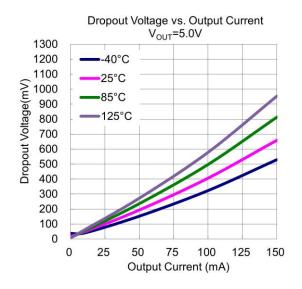


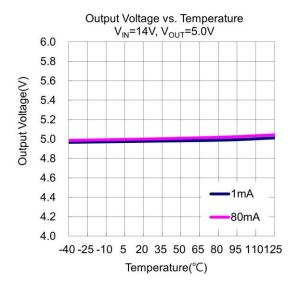


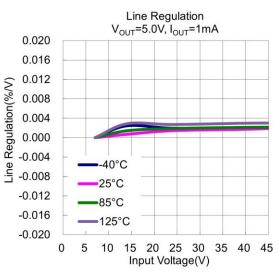




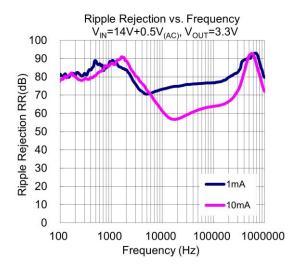


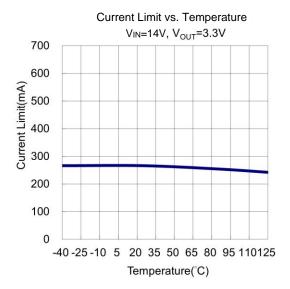


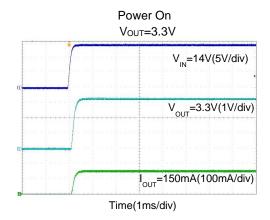


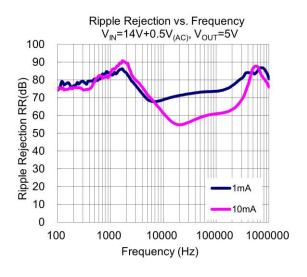


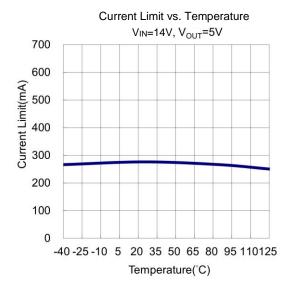


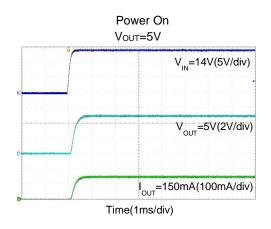




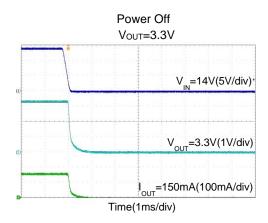


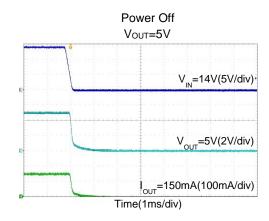


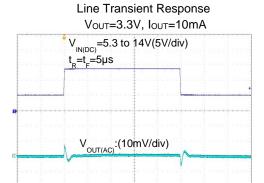




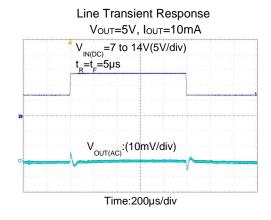


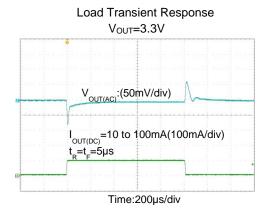


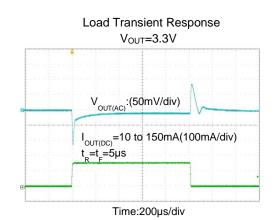




Time:200µs/div



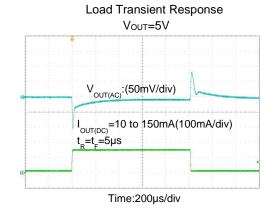






Load Transient Response Vout=5V $V_{\text{OUT(AG)}}:(50\text{mV/div})$ $I_{\text{OUT(DC)}}=10 \text{ to } 100\text{mA}(100\text{mA/div})$ $t_{\text{R}}=t_{\text{F}}=5\mu\text{s}$

Time:200µs/div



July 2025



Application Information

Output Capacitor

An output capacitor is required for the stability of the LDO. The recommended minimum output capacitance is 1µF. A ceramic capacitor is recommended, and temperature characteristics are X7R or X5R. Higher capacitance values help to improve load/line transient response. The output capacitance may be increased to keep low undershoot/overshoot. Place the output capacitor as close as possible to VOUT and GND pins.

Input Capacitor

A 1µF ceramic capacitor is recommended to connect between VIN and GND pins to decouple input power supply glitch and noise. The amount of the capacitance may be increased without limit. This input capacitor must be located as close as possible to the device to assure input stability and less noise. For PCB layout, a wide copper trace is required for both VIN and GND.

Current-Limit and Short-Circuit Protection

When output current at VOUT pin is higher than current-limit threshold or the VOUT pin directly shorts to GND, current-limit protection will trigger and clamp the output current at a pre-designed level to prevent overcurrent and thermal damage.

Thermal Protection

The AP7369Q has internal thermal sense and protection circuits. When excessive power dissipation happens on the device, such as short circuit at the output pin or very heavy load current with a large voltage drop across the device, the internal thermal protection circuit will trigger, shutting down the power MOSFET to prevent the LDO from damage. As soon as the excessive thermal condition is removed and the temperature of the device drops down, the thermal protection circuit will release the control of the power MOSFET, and the LDO device returns to normal operation.

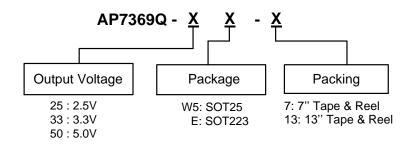
Layout Considerations

For good ground loop and stability, the input and output capacitors should be located close to the input, output, and ground pins of the device. The regulator ground pin should be connected to the external circuit ground to reduce voltage drop caused by trace impedance. Ground plane is generally used to reduce trace impedance. Wide trace should be used for large current paths from VIN to VOUT, and load circuit.

10 of 15 AP7369Q © 2025 Copyright Diodes Incorporated. All Rights Reserved. Document number: DS46899 Rev. 4 - 2 www.diodes.com



Ordering Information (Note 8)



Orderable Part Number Package Code	Packago Codo	Dockers	Packing	
	Package	Qty.	Carrier	
AP7369Q-XXW5-7	W5	SOT25	3,000	7" Tape & Reel
AP7369Q-XXE-13	E	SOT223	2,500	13" Tape & Reel

Note: 8. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

(1) SOT25

(Top View)

5 4 <u>XXXX</u> <u>Y W X</u>

2

1

3

XXXX: Identification Code

Y: Year 0 to 9

W: Week: A to Z: 1 to 26 week;

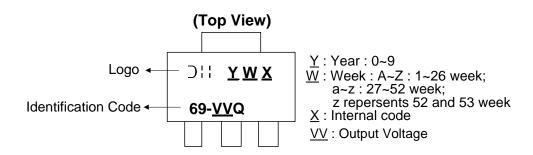
a to z : 27 to 52 week; z represents

52 and 53 week

X: Internal Code

Orderable Part Number	Package	Identification Code
AP7369Q-25W5-7	SOT25	2AAQ
AP7369Q-33W5-7	SOT25	2ACQ
AP7369Q-50W5-7	SOT25	2ADQ

(2) SOT223



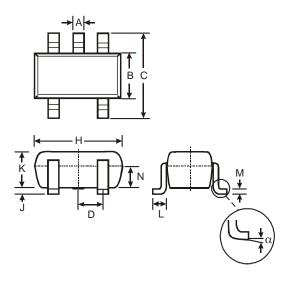
Orderable Part Number	Package	Identification Code
AP7369Q-25E-13	SOT223	69-25Q
AP7369Q-33E-13	SOT223	69-33Q
AP7369Q-50E-13	SOT223	69-50Q



Package Outline Dimensions

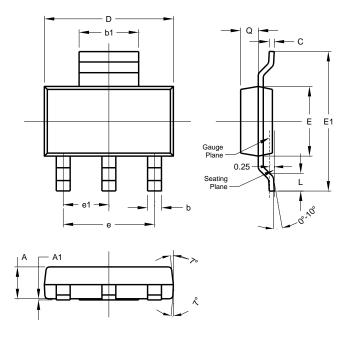
Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT25



	SOT25				
Dim	Min	Max	Тур		
Α	0.35	0.50	0.38		
В	1.50	1.70	1.60		
C	2.70	3.00	2.80		
D	-	-	0.95		
Η	2.90	3.10	3.00		
7	0.013	0.10	0.05		
K	1.00	1.30	1.10		
١	0.35	0.55	0.40		
М	0.10	0.20	0.15		
2	0.70	0.80	0.75		
α	0°	8°	-		
All [Dimens	ions ir	n mm		

SOT223



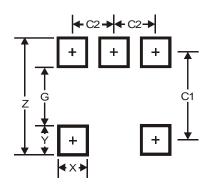
SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A 1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
C	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
١	0.85	1.05	0.95		
Ø	0.84	0.94	0.89		
All [All Dimensions in mm				



Suggested Pad Layout

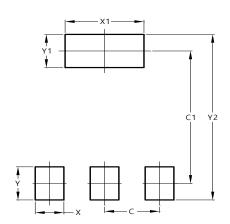
Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT25



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Y	0.80
C1	2.40
C2	0.95

SOT223



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8 00

Mechanical Data

SOT25

- Moisture Sensitivity: Level 1 Per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.018 grams (Approximate)

SOT223

- Moisture Sensitivity: Level 1 Per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.113 grams (Approximate)



IMPORTANT NOTICE

- DIODES INCORPORATED (Diodes) AND ITS SUBSIDIARIES MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).
- The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes' products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes' products. Diodes' products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of Diodes' products for their intended applications, (c) ensuring their applications, which incorporate Diodes' products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, guality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.
- Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and
- Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.
- provided subject Diodes' Standard (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.
- 6. Diodes' products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes' products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.
- While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.
- Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.
- 9. This Notice may be periodically updated with the most recent version available at https://www.diodes.com/about/company/terms-andconditions/important-notice

The Diodes logo is a registered trademark of Diodes Incorporated in the United States and other countries. All other trademarks are the property of their respective owners. © 2025 Diodes Incorporated, All Rights Reserved.

www.diodes.com

15 of 15 July 2025 AP7369Q © 2025 Copyright Diodes Incorporated. All Rights Reserved.